

P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}$ (Ω)	I _D (A) ^{a, e}	Q _g (Typ.)		
- 30	0.052 at V _{GS} = - 10 V	- 5.6	7 nC		
- 30	0.066 at V _{GS} = - 4.5 V	- 4.6	7110		

(SOT-23-3L)

Top View

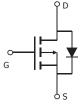
FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested



APPLICATIONS

- Load Switch
- Notebook Adaptor Switch
- DC/DC Converter



P-Channel MOSFET

- 55 to 150



ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter	Symbol	Limit	Unit			
Drain-Source Voltage	V _{DS}	- 30	V			
Gate-Source Voltage		V_{GS}	± 20	V		
	T _C = 25 °C		- 5.6			
Continuous Proin Current (T = 150 °C)	T _C = 70 °C	I _D	- 4.7			
Continuous Drain Current (T _J = 150 °C)	T _A = 25 °C		- 4.2 ^{b, c}			
	T _A = 70 °C	1	- 3.3 ^{b, c}	A		
Pulsed Drain Current		I _{DM}	- 22			
Continous Source-Drain Diode Current	T _C = 25 °C	- I _S	- 5.6			
Continuos Source-Diam Diode Current	T _A = 25 °C		- 1.5 ^{b, c}			
	T _C = 25 °C	P _D	2.5			
Maximum Dawar Dissipation	T _C = 70 °C		1.6	w		
Maximum Power Dissipation	T _A = 25 °C		1.25 ^{b, c}	VV		
	T ₄ = 70 °C	1	O 8b, c			

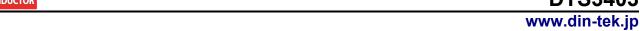
THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^{b, d}	t ≤ 5 s	R _{thJA}	75	100	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	40	50	_ C/VV	

- a. Based on T_C = 25 °C.
 b. Surface Mounted on 1" x 1" FR4 board.
- d. Maximum under Steady State conditions is 166 °C/W.

Operating Junction and Storage Temperature Range

e. Package Limited.

°C



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	•						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = - 250 μA		- 19		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	ΙD = - 250 μΑ		4.4			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 1.2		- 2.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zara Cata Valtaga Drain Current		V _{DS} = - 24 V, V _{GS} = 0 V			- 1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 24 V, V _{GS} = 0 V, T _J = 55 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 5.6			Α	
Drain Course On State Registered	P	V _{GS} = - 10 V, I _D = - 3 A		0.052	0.060		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 2A		0.066	0.070	Ω	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 3 A		10		S	
Dynamic ^b							
Input Capacitance	C _{iss}			1120		pF	
Output Capacitance	C _{oss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		115			
Reverse Transfer Capacitance	C _{rss}	1		93			
Total Cata Charge	Qg	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -3 \text{ A}$		7	11	nC	
Total Gate Charge				5			
Gate-Source Charge	Q_{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -2 \text{ A}$		2.1			
Gate-Drain Charge	Q_{gd}			2.9			
Gate Resistance	R_g	f = 1 MHz	1	5	10	Ω	
Turn-On Delay Time	t _{d(on)}			21		- ns	
Rise Time	t _r	V_{DD} = - 15 V, R_L = 4.5 Ω		20			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 2 A, V_{GEN} = - 4.5 V, R_g = 1 Ω		12			
Fall Time	t _f			8			
Turn-On Delay Time	t _{d(on)}			8			
Rise Time	t _r	V_{DD} = - 15 V, R_L = 4.5 Ω		18			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -3 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		15			
Fall Time	t _f]		6			
Drain-Source Body Diode Characteristi	cs						
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			- 5.6	Δ	
Pulse Diode Forward Current	I _{SM}				- 22	A	
Body Diode Voltage	V _{SD}	I _S = - 3.3 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			15	25	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	Q_{rr} $I_F = -3.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 °C$		9	19	nC	
Reverse Recovery Fall Time	t _a	- 1 3.3 Δ, αι/αι = 100 Α/μ5, 1J = 25 C		10		200	
Reverse Recovery Rise Time	t _b			7		ns	

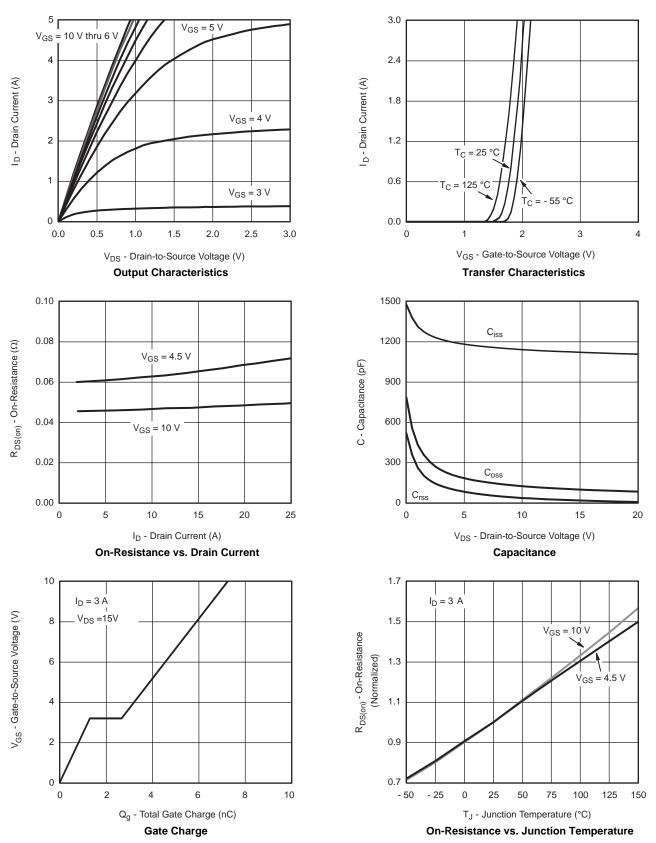
Din-Tek

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

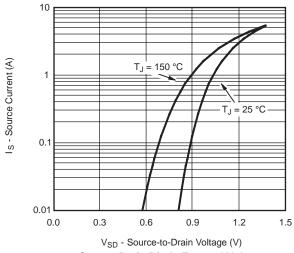


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

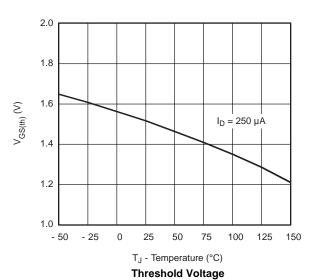




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



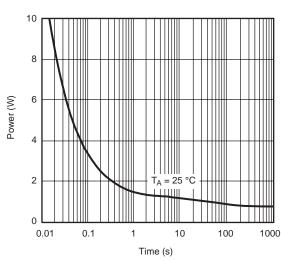
Source-Drain Diode Forward Voltage



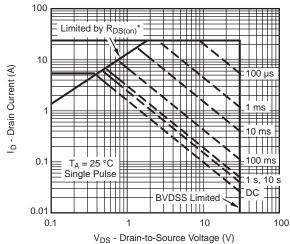
 $C_{\text{O}} = 3.4$ C_{\text

V_{GS} - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power (Junction-to-Ambient)

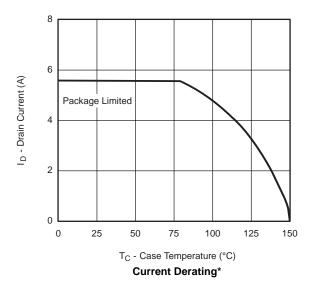


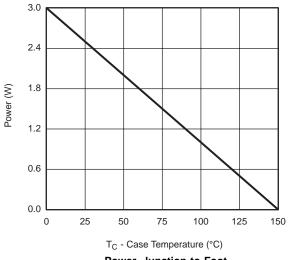
* V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

Safe Operating Area, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



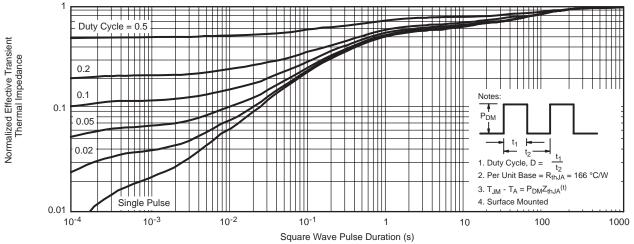


Power, Junction-to-Foot

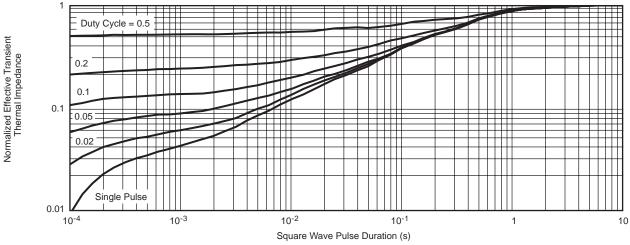
^{*} The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

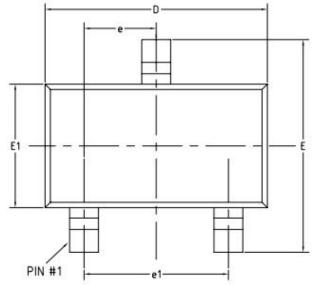
Note

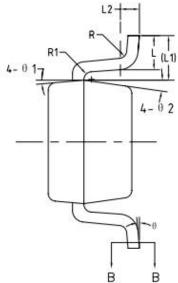
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

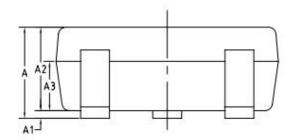
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

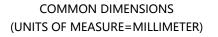


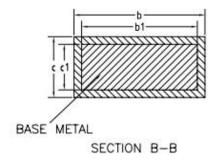
SOT-23-3L PACKAGE OUTLINE











SYMBOL	MIN	TYP	MAX
Α	ı	-	1.50
A1	0.00	-	0.18
A2	0.85	1.10	1.35
A3	0.58	0.65	0.72
b	0.23	1	0.53
b1	0.20	0.40	0.50
С	0.09	ı	0.22
c1	0.08	0.13	0.21
D	2.78	2.95	3.10
E	2.58	2.80	3.03
E1	1.55	1.65	1.78
е	0.83	0.95	1.07
e1	1.78	1.90	2.02
L	0.28	0.45	0.62
L1	0.59REF		
L2	0.25BSC		
R	0.04		
R1	0.04		0.21
θ	0°	-	8°
θ1	8°	10°	12°
θ2	8°	10°	12°





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